

Vishay Semiconductors

# Standard Diodes, 600 A (SUPER MAGN-A-PAK Power Modules)



**SUPER MAGN-A-PAK** 

PRODUCT SUMMARY			
I <sub>F(AV)</sub>	600 A		
Туре	Modules - Diode, High Voltage		

#### **FEATURES**

- High current capability
- High surge capability
- High voltage ratings up to 2000 V
- 3000 V<sub>RMS</sub> isolating voltage with non-toxic substrate
- Industrial standard package
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC

#### **TYPICAL APPLICATIONS**

- Rectifying bridge for large motor drives
- Rectifying bridge for large UPS

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
		600	A	
I <sub>F(AV)</sub>	T <sub>C</sub>	100	°C	
1		942	А	
I <sub>F</sub> (RMS)	T <sub>C</sub>	100	°C	
I <sub>FSM</sub>	50 Hz	19 000	۸	
	60 Hz	20 100	Α	
I <sup>2</sup> t	50 Hz	1805	kA <sup>2</sup> s	
1-1	60 Hz	1683		
I²√t		18 050	kA²√s	
V <sub>RRM</sub>	Range	800 to 2000	V	
T <sub>Stg</sub> , T <sub>J</sub>	Range	- 40 to 150	°C	

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> MAXIMUM mA		
	08	800	900			
VEKDEOO	12	1200	1300			
VSKD600 16		1600	1700	50		
	20	2000	2100			

### **VSKD600 Series**

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current	1	180° conduction, half sine wave		600	А	
at case temperature	I <sub>F(AV)</sub>	160 Condu	ction, nan sine wa	ave	100	°C
Maximum RMS forward current	I <sub>F(RMS)</sub>	180° condu	ction, half sine wa	ave at T <sub>C</sub> = 100 °C	942	Α
		t = 10 ms	No voltage		19.0	- kA
Maximum peak, one-cycle forward,	1	t = 8.3  ms	reapplied		20.1	
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub> reapplied	Sinusoidal half wave,	16.2	
		t = 8.3 ms			17.2	
20.6	t = 10  ms $t = 8.3  ms$ $t = 10  ms$ $t = 10  ms$ $t = 8.3  ms$	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	1805	1.02-
		t = 8.3 ms	reapplied		1683	
Maximum I <sup>2</sup> t for fusing		100 % V <sub>RRM</sub>		1319	kA <sup>2</sup> s	
		t = 8.3 ms	reapplied		1230	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied		18 050	kA²√s	
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum		0.70	V	
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.77	V	
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum		0.28		
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum} $ 0.25			0.25	mΩ
Maximum forward voltage drop	$V_{FM}$	I <sub>pk</sub> = 1800 A, T <sub>J</sub> = 25 °C, t <sub>p</sub> = 10 ms sine pulse 1.45			V	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
RMS insulation voltage	V <sub>INS</sub>	t = 1 s	3000	V
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub>	$T_J = T_J$ maximum, rated $V_{RRM}$ applied	50	mA

THERMAL AND	THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction op temperature range	erating and storage	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C
Maximum thermal resistance, junction to case per junction		R <sub>thJC</sub>	DC operation	0.065	K/W
Maximum thermal resistance, case to heatsink		R <sub>thC-hs</sub>		0.02	r∨ vv
Mounting torque	SMAP to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow		Nm
± 10 %	busbar to SMAP		for the spread of the compound.	12 to 15	INIII
Approximate weight				1500	g
Case style			See dimensions - link at the end of datasheet	SUPER MAG	N-A-PAK



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△R <sub>thJC</sub> CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.009	0.006		
120°	0.011	0.011		
90°	0.014	0.015	$T_J = T_J$ maximum	K/W
60°	0.021	0.022		
30°	0.037	0.038		

#### Note

• The table above shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

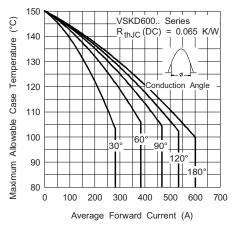


Fig. 1 - Current Ratings Characteristics

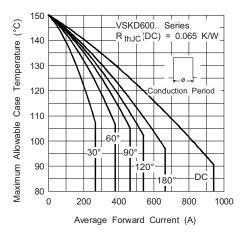


Fig. 2 - Current Ratings Characteristics

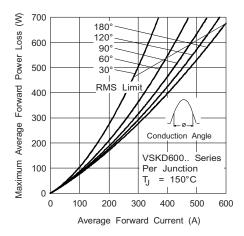


Fig. 3 - Forward Power Loss Characteristics

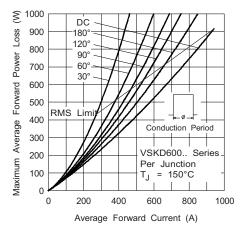


Fig. 4 - Forward Power Loss Characteristics

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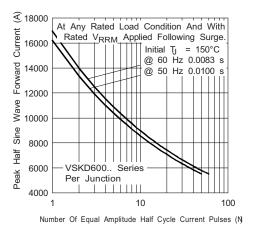


Fig. 5 - Maximum Non-Repetitive Surge Current

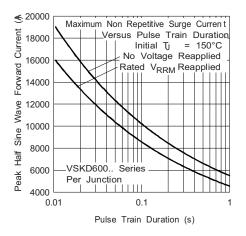


Fig. 6 - Maximum Non-Repetitive Surge Current

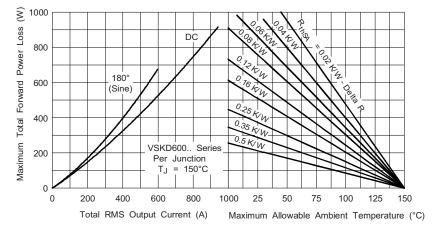


Fig. 7 - Forward Power Loss Characteristics

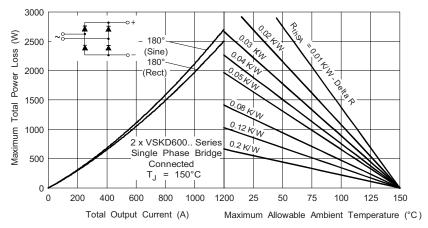


Fig. 8 - Forward Power Loss Characteristics



## Standard Diodes, 600 A (SUPER MAGN-A-PAK Power Modules)

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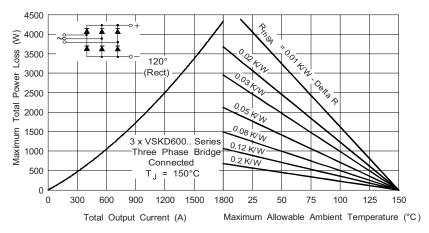


Fig. 9 - Forward Power Loss Characteristics

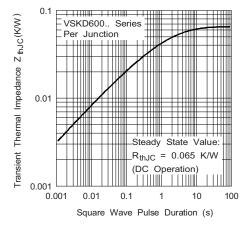


Fig. 10 - Thermal Impedance  $Z_{thJC}$  Characteristic

### **VSKD600 Series**

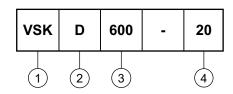
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### **ORDERING INFORMATION TABLE**

Device code



- 1 Module type
- Circuit configuration D = 2 diodes in series
   (see Circuit Configuration table)
- 3 Current rating
- Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)

CIRCUIT CONFIGURATION			
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING	
Two diodes doubler circuit	D	20 0 1	

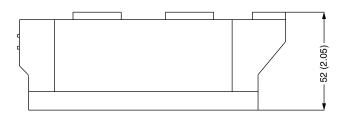
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95088	

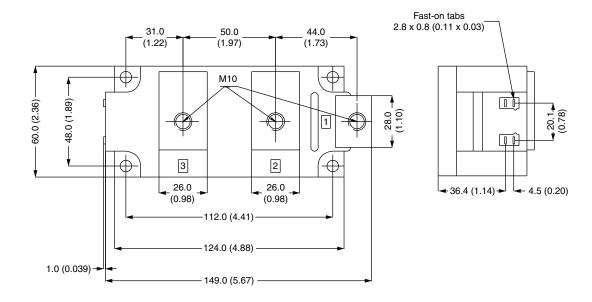


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## **Super MAGN-A-PAK Diode**

### **DIMENSIONS** in millimeters (inches)







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